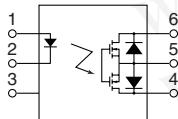
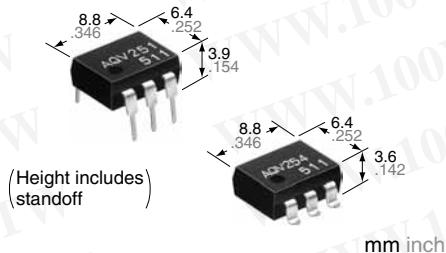


Both low on-resistance and good cost-performance achieved.

PhotoMOS®
HE 1 Form A
(AQV25O)



RoHS compliant

FEATURES

1. Wide variation of 40V, 60V, 100V, 200V, 250V, 400V, 600V, 1,000V and 1,500V load voltage
2. Low on-resistance of typ. 0.6Ω (AQV251)
3. Reinforced insulation type of 5,000V I/O isolation available

TYPICAL APPLICATIONS

- Measuring instruments
- Data communication equipment
- Telephone equipment
- Automatic meter reading device

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胜特力电子(上海) 86-21-34970699
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TYPES

I/O isolation	Output rating*	Output rating*		Package	Part No.				Packing quantity				
		Load voltage	Load current		Through hole terminal		Surface-mount terminal						
					Tube packing style		Tape and reel packing style						
AC/DC dual use	1,500V	40 V	500 mA	DIP6-pin	AQV251	AQV251A	AQV251AX	AQV251AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.			
		60 V	400 mA		AQV252	AQV252A	AQV252AX	AQV252AZ					
		100 V	350 mA		AQV255	AQV255A	AQV255AX	AQV255AZ					
		200 V	250 mA		AQV257	AQV257A	AQV257AX	AQV257AZ					
		250 V	200 mA		AQV253	AQV253A	AQV253AX	AQV253AZ					
		400 V	150 mA		AQV254	AQV254A	AQV254AX	AQV254AZ					
		1,000 V	30 mA		AQV259	AQV259A	AQV259AX	AQV259AZ					
		1,500 V	20 mA		AQV258	AQV258A	AQV258AX	AQV258AZ					
	Reinforced 5,000V <i>New</i>	250 V	200 mA		AQV253H	AQV253HA	AQV253HAX	AQV253HAZ					
		400 V	150 mA		AQV254H	AQV254HA	AQV254HAX	AQV254HAZ					
		600 V	130 mA		AQV256H	AQV256HA	AQV256HAX	AQV256HAZ					

*Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

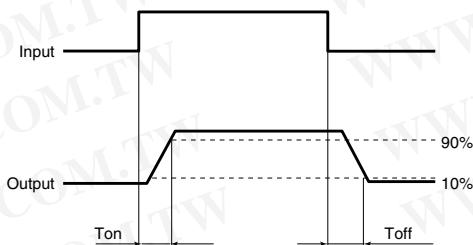
Item	Symbol	Type of connection	AQV251(A)	AQV252(A)	AQV255(A)	AQV257(A)	AQV253(A)	AQV254(A)	AQV259(A)	AQV258(A)	AQV253H(A)	AQV254H(A)	AQV256H(A)	Remarks															
Input	LED forward current	I _F	A	50 mA																									
	LED reverse voltage	V _R		5 V																									
	Peak forward current	I _{FP}		1 A																									
Output	Power dissipation	P _{in}	75 mW											f = 100 Hz, Duty factor +0.1%															
	Load voltage (peak AC)	V _L	40V	60V	100V	200V	250V	400V	1,000V	1,500V	250V	400V	600V																
	Continuous load current	I _L	A	0.5A	0.4A	0.35A	0.25A	0.2A	0.15A	0.03A	0.02A	0.2A	0.15A	0.13A															
	Peak load current	I _{peak}	B	0.7A	0.6A	0.45A	0.35A	0.3A	0.18A	0.04A	0.025A	0.3A	0.18A	0.14A	A connection: Peak AC, DC B, C connection: DC														
	Power dissipation	P _{out}	C	1.0A	0.8A	0.70A	0.5A	0.4A	0.25A	0.05A	0.04A	0.4A	0.25A	0.16A															
	Total power dissipation	P _T	360 mW																										
Temperature limits	I/O isolation voltage	V _{iso}	410 mW											Non-condensing at low temperatures															
	Operating	T _{opr}	1,500 V AC																										
	Storage	T _{stg}	5,000 V AC																										
-40°C to +85°C -40°F to +185°F																													
-40°C to +100°C -40°F to +212°F																													

HE 1 Form A (AQV25O)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV251(A)	AQV252(A)	AQV255(A)	AQV257(A)	AQV253(A)	AQV254(A)	AQV259(A)	AQV258(A)	AQV253H(A)	AQV254H(A)	AQV256H(A)	Condition	
Input	LED operate current	Typical	I_{Fon}	0.9 mA				1.4 mA				$I_L = \text{Max.}$				
	Maximum	—		3 mA				1.4 mA				$I_L = \text{Max.}$				
Input	LED turn off current	Minimum	I_{Foff}	0.4 mA				1.3 mA				$I_L = \text{Max.}$				
	Typical	—		0.8 mA				1.3 mA				$I_L = \text{Max.}$				
Input	LED dropout voltage	Typical	V_F	1.25 V (1.14 V at $I_F = 5 \text{ mA}$)				1.5 V				$I_F = 50 \text{ mA}$				
	Maximum	—		1.5 V				1.5 V				$I_F = 50 \text{ mA}$				
Output	On resistance	Typical	R_{on}	A	0.6 Ω	0.74 Ω	1.8 Ω	2.6 Ω	5.5 Ω	12.4 Ω	85 Ω	345 Ω	5.5 Ω	12.4 Ω	20 Ω	
	Maximum	—			1 Ω	1.4 Ω	2.5 Ω	4 Ω	8 Ω	16 Ω	200 Ω	500 Ω	8 Ω	16 Ω	30 Ω	
	On resistance	Typical	R_{on}	B	0.3Ω	0.37 Ω	0.9 Ω	1.4 Ω	2.7 Ω	6.2 Ω	60 Ω	345 Ω	2.7 Ω	6.2 Ω	15 Ω	
	Maximum	—			0.5 Ω	0.7 Ω	1.25 Ω	2 Ω	4 Ω	8 Ω	100 Ω	500 Ω	4 Ω	8 Ω	20 Ω	
	On resistance	Typical	R_{on}	C	0.15 Ω	0.18 Ω	0.45 Ω	0.7 Ω	1.4 Ω	3.1 Ω	30 Ω	160 Ω	1.4 Ω	3.1 Ω	7.5 Ω	
	Maximum	—			0.25 Ω	0.35 Ω	0.63 Ω	1 Ω	2 Ω	4 Ω	50 Ω	250 Ω	2 Ω	4 Ω	10 Ω	
	Off state leakage current	Maximum	I_{Leak}	—	1 μA				10 μA				1 μA			
Transfer characteristics	Turn on time*	Typical	T_{on}	—	1.7 ms	1.4 ms	0.9 ms	1.5 ms	0.8 ms		0.6 ms	0.35 ms	2.4 ms	1.8 ms	1.2 ms	
	Maximum	—		—	3 ms	2 ms	3 ms	2 ms	1 ms		4 ms	3ms				
	Turn off time*	Typical	T_{off}	—	0.07 ms				0.09 ms	0.1 ms	0.06 ms	0.05 ms	0.04 ms			
	Maximum	—		—	0.2 ms				0.1 ms				0.06 ms			
	I/O capacitance	Typical	C_{iso}	—	1.3 pF				3 pF				$f = 1 \text{ MHz}$			
	Initial I/O isolation resistance	Minimum	R_{iso}	—	1,000 MΩ				1,000 MΩ				$V_B = 0 \text{ V}$			

*Turn on/Turn off time



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RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I_F	Standard type: 5 Reinforced insulation type: 5 to 10	mA

■ For Dimensions.

■ For Schematic and Wiring Diagrams.

■ For Cautions for Use.

■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

For more information.

■ Continual DC bias (for AQV258**, AQV259**)

In cases in which a continual DC bias is applied between the input and output, the output-side MOS-FET may deteriorate due to the voltage. Therefore, please verify operation of the actual design before using. An example of a circuit that might undergo MOS-FET deterioration due to voltage is given below.

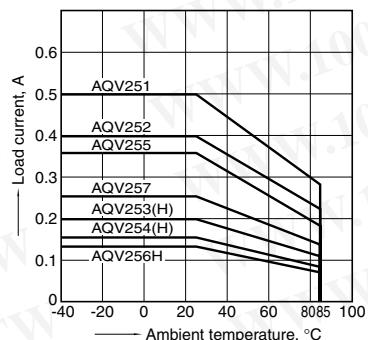
HE 1 Form A (AQV25O)

REFERENCE DATA

1.- (1) Load current vs. ambient temperature characteristics

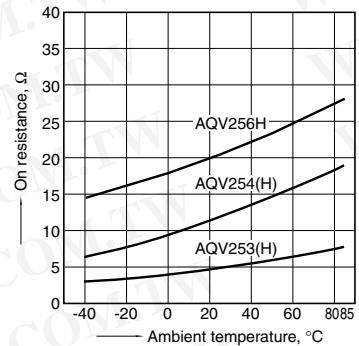
Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$;

Type of connection: A



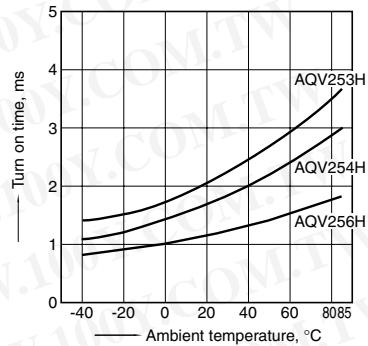
2.- (2) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
 LED current: 5 mA;
 Continuous load current: Max. (DC)



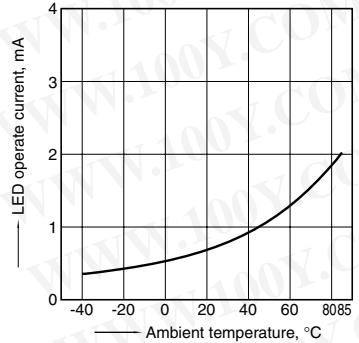
3.- (2) Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



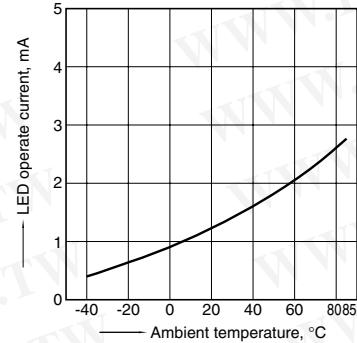
5.- (1) LED operate current vs. ambient temperature characteristics

Sample: AQV251, AQV252, AQV253, AQV254, AQV255, AQV258, AQV259; Load voltage: Max. (DC); Continuous load current: Max. (DC)



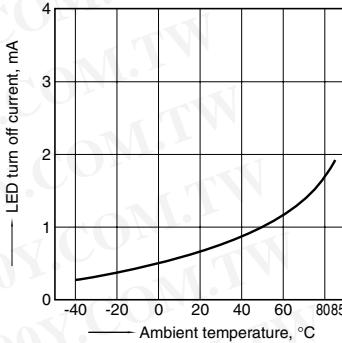
5.- (2) LED operate current vs. ambient temperature characteristics

Sample: AQV253H, AQV254H, AQV256H; Load voltage: Max. (DC); Continuous load current: Max. (DC)

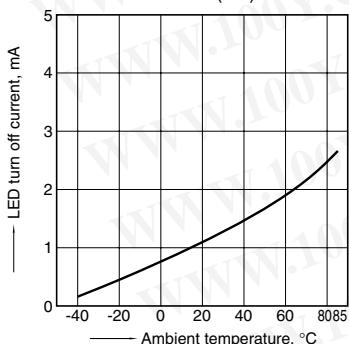


6.- (1) LED turn off current vs. ambient temperature characteristics

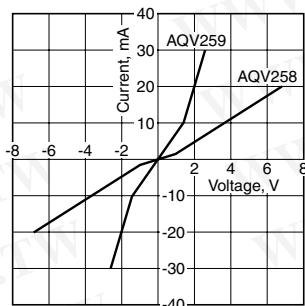
Sample: AQV251, AQV252, AQV253, AQV254, AQV255, AQV258, AQV259; Load voltage: Max. (DC); Continuous load current: Max. (DC)



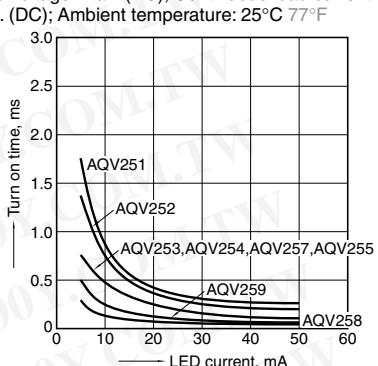
6.-2) LED turn off current vs. ambient temperature characteristics
 Sample: AQV253H, AQV254H, AQV256H;
 Load voltage: Max. (DC);
 Continuous load current: Max. (DC)



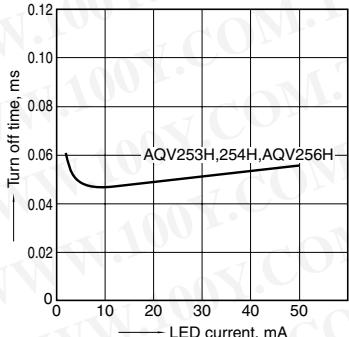
8.-2) Current vs. voltage characteristics of output at MOS portion
 Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



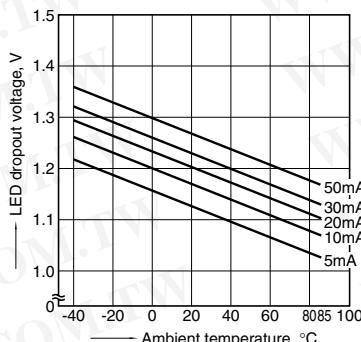
10-(1). Turn on time vs. LED forward current characteristics
 Measured portion: between terminals 4 and 6;
 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



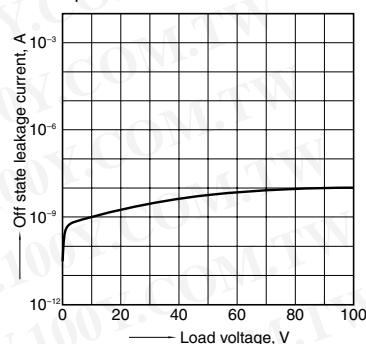
11-(2). Turn off time vs. LED forward current characteristics
 Measured portion: between terminals 4 and 6;
 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



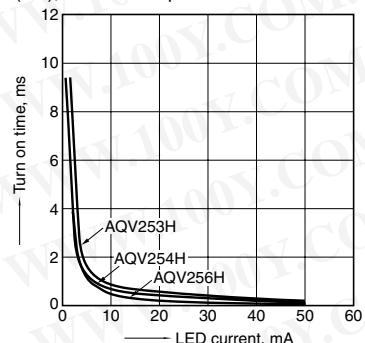
7. LED dropout voltage vs. ambient temperature characteristics
 LED current: 5 to 50 mA



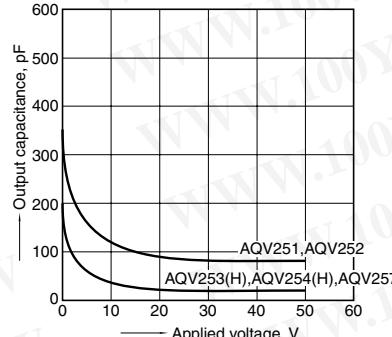
9-(1). Off state leakage current vs. load voltage characteristics
 Sample: AQV259;
 Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



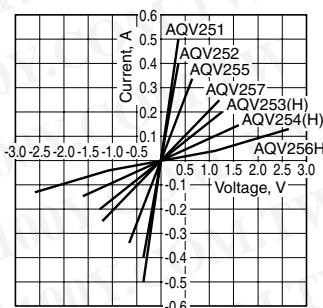
10-(2). Turn on time vs. LED forward current characteristics
 Measured portion: between terminals 4 and 6;
 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



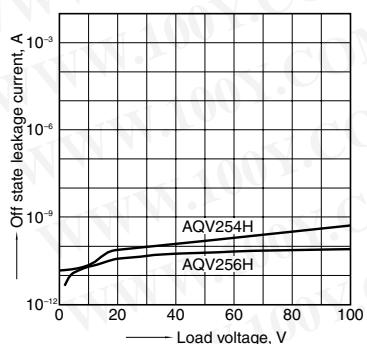
12.-1) Output capacitance vs. applied voltage characteristics
 Measured portion: between terminals 4 and 6;
 Frequency: 1 MHz;
 Ambient temperature: 25°C 77°F



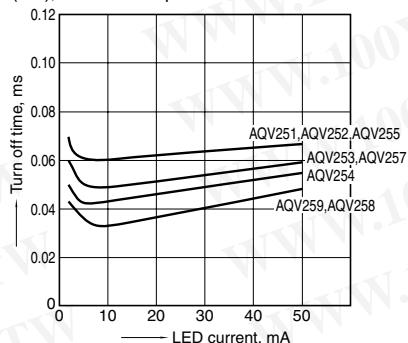
8.-1) Current vs. voltage characteristics of output at MOS portion
 Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



9-(2). Off state leakage current vs. load voltage characteristics
 Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



11-(1). Turn off time vs. LED forward current characteristics
 Measured portion: between terminals 4 and 6;
 Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12.-2) Output capacitance vs. applied voltage characteristics
 Sample: AQV259;
 Measured portion: between terminals 4 and 6;
 Frequency: 1 MHz; Ambient temperature: 25°C 77°F

